# MMBFJ309L, MMBFJ310L, SMMBFJ309L, SMMBFJ310L

# JFET - VHF/UHF Amplifier Transistor

# **N–Channel**

#### Features

- Drain and Source are Interchangeable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	25	Vdc
Gate-Source Voltage	V <sub>GS</sub>	25	Vdc
Gate Current	I <sub>G</sub>	10	mAdc

#### THERMAL CHARACTERISTICS

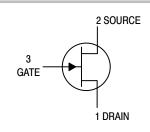
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	556	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.



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SOT-23 (TO-236) CASE 318 STYLE 10

#### MARKING DIAGRAM



6x = Device Code

- x = U for MMBFJ309L, SMMBFJ309L
- x = T for MMBFJ310L, SMMBFJ310L
- M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBFJ309LT1G,	SOT-23	3,000 / Tape &
SMMBFJ309LT1G	(Pb-Free)	Reel
MMBFJ310LT1G,	SOT-23	3,000 / Tape &
SMMBFJ310LT1G	(Pb-Free)	Reel
SMMBFJ310LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

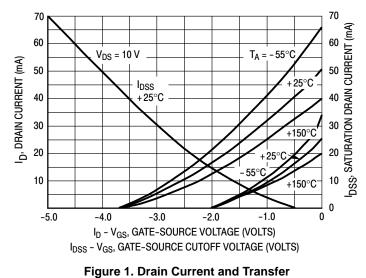
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## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

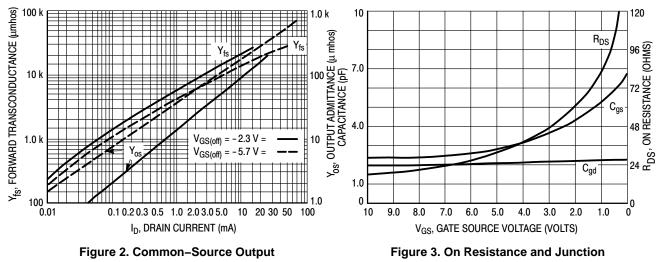
Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Gate–Source Breakdown Voltage $(I_G = -1.0 \ \mu Adc, \ V_{DS} = 0)$		V <sub>(BR)GSS</sub>	-25	-	-	Vdc
Gate Reverse Current ( $V_{GS} = -15$ Vdc) ( $V_{GS} = -15$ Vdc, $T_A = 125^{\circ}C$ )		I <sub>GSS</sub>	-	-	-1.0 -1.0	nAdc μAdc
Gate Source Cutoff Voltage $(V_{DS} = 10 \text{ Vdc}, I_D = 1.0 \text{ nAdc})$	MMBFJ309 MMBFJ310, SMMBFJ310	V <sub>GS(off)</sub>	-1.0 -2.0	-	-4.0 -6.5	Vdc
ON CHARACTERISTICS						
Zero–Gate–Voltage Drain Current $(V_{DS} = 10 \text{ Vdc}, V_{GS} = 0)$	MMBFJ309 MMBFJ310, SMMBFJ310	I <sub>DSS</sub>	12 24		30 60	mAdc
Gate-Source Forward Voltage $(I_G = 1.0 \text{ mAdc}, V_{DS} = 0)$		V <sub>GS(f)</sub>	-	-	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS						
Forward Transfer Admittance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$		Y <sub>fs</sub>	8.0	-	18	mmhos
Output Admittance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$		y <sub>os</sub>	-	_	250	μmhos
Input Capacitance (V <sub>GS</sub> = -10 Vdc, V <sub>DS</sub> = 0 Vdc, f = 1.0 MHz)		C <sub>iss</sub>	-	-	5.0	pF
Reverse Transfer Capacitance $(V_{GS} = -10 \text{ Vdc}, V_{DS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$		C <sub>rss</sub>	-	-	2.5	pF
Equivalent Short–Circuit Input Noise Voltage $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 100 \text{ Hz})$		e <sub>n</sub>	-	10	_	$nV/\sqrt{Hz}$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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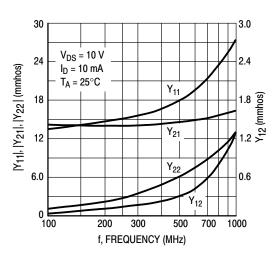
Characteristics versus Gate–Source Voltage



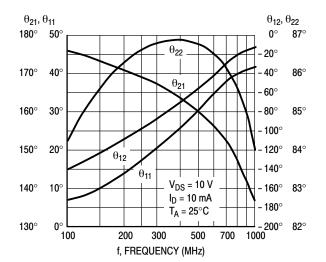
Admittance and Forward Transconductance versus Drain Current

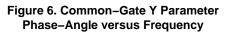
Capacitance versus Gate-Source Voltage

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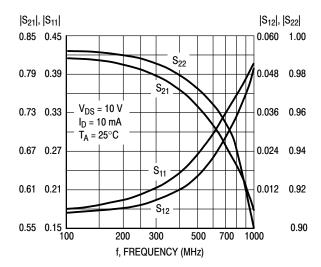
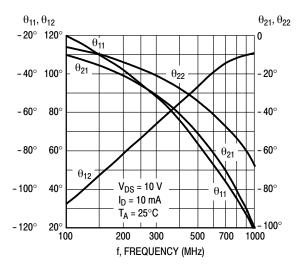
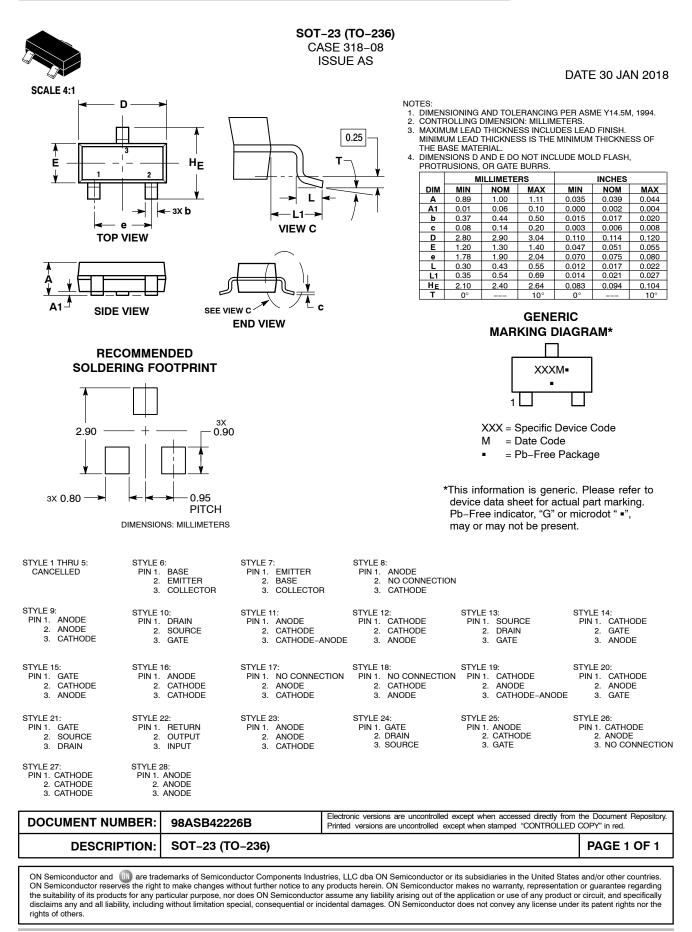


Figure 5. Common–Gate S Parameter Magnitude versus Frequency









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